

L Number	Hits	Search Text	DB	Time stamp
5	15	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same vanadium	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:41
6	103	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same (titanium or vanadium or tantalum)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:45
7	69	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same (titanium)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:44
8	48	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same (tantalum)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:45
9	3	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same (titanium or vanadium or tantalum) near10 dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:49
10	8	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same (arsenic) near10 dop\$4	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:51
11	12	((sic or silicon adj carbide) near5 (single near2 (crystal or crystallin\$4))) same (arsenic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 13:51
44	11	atomic near3 radius near10 (silicon and carbon)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 14:39
45	31	atomic near3 radius near10 aluminum	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 14:41
55	124	n\$1type near5 (silicon adj carbide or sic) near10 concentration	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 17:09
56	13	n\$1type near5 (silicon adj carbide or sic) near10 concentration near10 single near2 crystal	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/14 17:10
-	126	((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (as or arsenic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/11 11:51
-	23	((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (as or arsenic) and 117/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/11 13:15
-	4	((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (arsenic) and 117/\$.ccls.	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/11 12:59

-	15	((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (arsenic)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/11 13:00
-	11	((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (arsenic)) not (((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (arsenic) and 117/\$.ccls.)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/11 13:00
-	17	((sic or silicon adj carbide) near10 (crystal or crystallin\$4)) same (dop\$4) near10 (titanium or vanadium or chromium or iron or manganese)	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/08/11 13:18